



EMK33 G 2 H -45.7867M

Series —
RoHS Compliant (Pb-free) 4 Pad 2.5mm x 3.2mm SMD 3.3Vdc LVCMOS MEMS Oscillator

Frequency Tolerance/Stability ±100ppm Maximum over -40°C to +85°C

Duty Cycle -50 ±5(%) Nominal Frequency 45.7867MHz

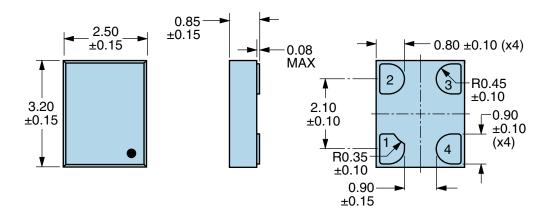
- Output Control Function Tri-State (Disabled Output: High Impedance)

| ELECTRICAL SPECIFICATIONS | | |
|---------------------------------|---|--|
| Nominal Frequency | 45.7867MHz | |
| Frequency Tolerance/Stability | ±100ppm Maximum over -40°C to +85°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration) | |
| Aging at 25°C | ±1ppm Maximum First Year | |
| Operating Temperature Range | -40°C to +85°C | |
| Supply Voltage | 3.3Vdc ±10% | |
| Input Current | 25mA Maximum | |
| Output Voltage Logic High (Voh) | 90% of Vdd Minimum (IOH=-8mA) | |
| Output Voltage Logic Low (Vol) | 10% of Vdd Maximum (IOL=+8mA) | |
| Rise/Fall Time | 2nSec Maximum (Measured from 20% to 80% of waveform) | |
| Duty Cycle | 50 ±5(%) (Measured at 50% of waveform) | |
| Load Drive Capability | 15pF Maximum | |
| Output Logic Type | CMOS | |
| Output Control Function | Tri-State (Disabled Output: High Impedance) | |
| Output Control Input Voltage | +0.7Vdd Minimum or No Connect to Enable Output, +0.3Vdd Maximum to Disable Output | |
| Peak to Peak Jitter (tPK) | 250pSec Maximum, 100pSec Typical | |
| Start Up Time | 50mSec Maximum | |
| Storage Temperature Range | -55°C to +125°C | |

| ENVIRONMENTAL & MECHANICAL SPECIFICATIONS | | |
|---|---|--|
| ESD Susceptibility | MIL-STD-883, Method 3015, Class 2, HBM 2000V | |
| Flammability | UL94-V0 | |
| Mechanical Shock | MIL-STD-883, Method 2002, Condition G, 30,000G | |
| Moisture Resistance | MIL-STD-883, Method 1004 | |
| Moisture Sensitivity Level | J-STD-020, MSL 1 | |
| Resistance to Soldering Heat | MIL-STD-202, Method 210, Condition K | |
| Resistance to Solvents | MIL-STD-202, Method 215 | |
| Solderability | MIL-STD-883, Method 2003 (Pads on Bottom of Package Only) | |
| Temperature Cycling | MIL-STD-883, Method 1010, Condition B | |
| Thermal Shock | MIL-STD-883, Method 1011, Condition B | |
| Vibration | MIL-STD-883, Method 2007, Condition A, 20G | |



MECHANICAL DIMENSIONS (all dimensions in millimeters)

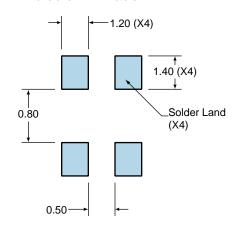


| PIN | CONNECTION |
|-----|----------------|
| 1 | Tri-State |
| 2 | Ground |
| 3 | Output |
| 4 | Supply Voltage |

| LINE | MARKING |
|------|---|
| 1 | XXXX or XXXXX XXXX or XXXXX=Ecliptek Manufacturing Lot Code |

Suggested Solder Pad Layout

All Dimensions in Millimeters



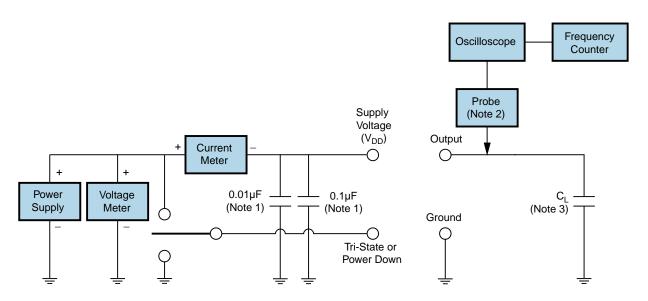
All Tolerances are ±0.1



OUTPUT WAVEFORM & TIMING DIAGRAM



Test Circuit for CMOS Output



- Note 1: An external 0.1µF low frequency tantalum bypass capacitor in parallel with a 0.01µF high frequency ceramic bypass capacitor close to the package ground and V_{DD} pin is required.
- Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.
- Note 3: Capacitance value \dot{C}_L includes sum of all probe and fixture capacitance.



Recommended Solder Reflow Methods



High Temperature Infrared/Convection

| T _s MAX to T _∟ (Ramp-up Rate) | 3°C/second Maximum |
|---|--------------------------------------|
| Preheat | |
| - Temperature Minimum (Ts MIN) | 150°C |
| - Temperature Typical (T _s TYP) | 175°C |
| - Temperature Maximum (T _s MAX) | 200°C |
| - Time (t _s MIN) | 60 - 180 Seconds |
| Ramp-up Rate (T _L to T _P) | 3°C/second Maximum |
| Time Maintained Above: | |
| - Temperature (T∟) | 217°C |
| - Time (t∟) | 60 - 150 Seconds |
| Peak Temperature (T _P) | 260°C Maximum for 10 Seconds Maximum |
| Target Peak Temperature (T _P Target) | 250°C +0/-5°C |
| Time within 5°C of actual peak (tp) | 20 - 40 seconds |
| Ramp-down Rate | 6°C/second Maximum |
| Time 25°C to Peak Temperature (t) | 8 minutes Maximum |
| Moisture Sensitivity Level | Level 1 |
| | |



Recommended Solder Reflow Methods



Low Temperature Infrared/Convection 240°C

| T _S MAX to T _L (Ramp-up Rate) | 5°C/second Maximum |
|---|--|
| Preheat | |
| - Temperature Minimum (T _s MIN) | N/A |
| - Temperature Typical (T _s TYP) | 150°C |
| - Temperature Maximum (T _s MAX) | N/A |
| - Time (t _s MIN) | 60 - 120 Seconds |
| Ramp-up Rate (T _L to T _P) | 5°C/second Maximum |
| Time Maintained Above: | |
| - Temperature (T∟) | 150°C |
| - Time (t∟) | 200 Seconds Maximum |
| Peak Temperature (T _P) | 240°C Maximum |
| Target Peak Temperature (T _P Target) | 240°C Maximum 1 Time / 230°C Maximum 2 Times |
| Time within 5°C of actual peak (tp) | 10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time |
| Ramp-down Rate | 5°C/second Maximum |
| Time 25°C to Peak Temperature (t) | N/A |
| Moisture Sensitivity Level | Level 1 |

Low Temperature Manual Soldering

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

High Temperature Manual Soldering

260°C Maximum for 5 seconds Maximum, 2 times Maximum.